**ON Semiconductor** 

Is Now

# Onsemi

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# MPSH10

Preferred Device

# **VHF/UHF Transistors**

## **NPN Silicon**

#### Features

• Pb-Free Packages are Available\*

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V <sub>CEO</sub>	25	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	30	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	3.0	Vdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	350 2.8	W mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.0 8.0	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

#### THERMAL CHARACTERISTICS

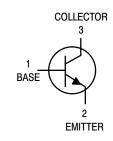
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200357	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	125	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



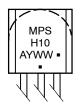
## **ON Semiconductor®**

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#### MARKING DIAGRAM



A = Assembly Location Y = Year WW = Work Week • = Pb-Free Package (Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## MPSH10

### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	·	•		
Collector – Emitter Breakdown Voltage $(I_{C} = 1.0 \text{ mAdc}, I_{B} = 0)$	V <sub>(BR)CEO</sub>	25	_	Vdc
Collector – Base Breakdown Voltage $(I_{C} = 100 \ \mu Adc, I_{E} = 0)$	V <sub>(BR)CBO</sub>	30	_	Vdc
Emitter – Base Breakdown Voltage ( $I_E = 10 \ \mu Adc, I_C = 0$ )	V <sub>(BR)EBO</sub>	3.0	_	Vdc
Collector Cutoff Current $(V_{CB} = 25 \text{ Vdc}, I_E = 0)$	I <sub>CBO</sub>	-	100	nAdc
Emitter Cutoff Current ( $V_{EB} = 2.0 \text{ Vdc}, I_C = 0$ )	I <sub>EBO</sub>	-	100	nAdc
ON CHARACTERISTICS		•		
DC Current Gain (I <sub>C</sub> = 4.0 mAdc, V <sub>CE</sub> = 10 Vdc)	h <sub>FE</sub>	60	_	_
Collector – Emitter Saturation Voltage ( $I_C = 4.0 \text{ mAdc}, I_B = 0.4 \text{ mAdc}$ )	V <sub>CE(sat)</sub>	-	0.5	Vdc
Base – Emitter On Voltage (I <sub>C</sub> = 4.0 mAdc, V <sub>CE</sub> = 10 Vdc)	V <sub>BE(on)</sub>	-	0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current – Gain – Bandwidth Product (I <sub>C</sub> = 4.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 100 MHz)	fT	650	_	MHz
Collector–Base Capacitance $(V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C <sub>cb</sub>	-	0.7	pF
Common-Base Feedback Capacitance $(V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C <sub>rb</sub>	0.35	0.65	pF
Collector Base Time Constant (I <sub>C</sub> = 4.0 mAdc, V <sub>CB</sub> = 10 Vdc, f = 31.8 MHz)	rb'C <sub>c</sub>	-	9.0	ps

#### **ORDERING INFORMATION**

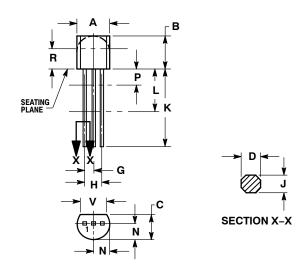
Device	Package	Shipping <sup>†</sup>
MPSH10	TO-92	5000 Units / Box
MPSH10G	TO-92 (Pb-Free)	5000 Units / Box
MPSH10RLRA	TO-92	2000 / Tape & Reel
MPSH10RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSH10RLRP	TO-92	2000 / Ammo Pack
MPSH10RLRPG	TO–92 (Pb–Free)	2000 / Ammo Pack

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

#### MPSH10

#### PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUF AI



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- 2 CONTOUR OF PACKAGE BEYOND DIMENSION R 3.
- IS UNCONTROLLED. 4.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
۷	0.135		3.43	

STYLE 2:

PIN 1. BASE

EMITTER
COLLECTOR

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Phone: 81-3-5773-3850

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 MCH4016-TL-H
 MMBT5551-G
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 15GN01CA-TB-E
 PH1214-25M
 MAPRST0912-350
 MMBTH10-TP
 BFP

 640F H6327
 BFP 720F H6327
 BFP 740F H6327
 BFR 360F H6765
 MRF10031
 NSVF4009SG4T1G
 BFP 182R E7764

 BFP405H6740XTSA1
 MRF10350
 ASMA201
 BFR360FH6765XTSA1
 BFP410H6327XTSA1
 BFP620FH7764XTSA1

 BFP720ESDH6327XTSA1
 BFP720FH6327XTSA1
 BFR360L3E6765XTMA1
 BFP420H6433XTMA1
 BFP420H6740XTSA1
 MCH4015-TL-H

 H
 BF888H6327XTSA1
 BFP720FH6327XTSA1
 BFR360L3E6765XTMA1
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 MCH4015-TL-H

 H
 BF888H6327XTSA1
 MMBT2222A-G
 BFP196WH6327XTSA1
 BFP405FH6327XTSA1
 BFP640ESDH6327XTSA1

 BFR193L3E6327XTMA1
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 MRF10005
 BFP420FH6327XTSA1

 BFP740FESDH6327XTSA1
 BFR181E6327HTSA1
 BFR181WH6327XTSA1
 BFR182E6327HTSA1
 BFR193E6327HTSA1

 BFP181E7764HTSA1
 BFP183WH6327XTSA1
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